## Amendments to the Claims

- 1. (original) A method of monitoring an integrated circuit chip, comprising:
- (a) receiving at least one digitized sense signal from the integrated circuit chip, whereby the at least one digitized sense signal represents a corresponding process-dependent parameter within the integrated circuit chip; and
- (b) determining an analog value for the at least one process-dependent circuit parameters from the corresponding at least one digitized signal;

wherein the process-dependent parameter is measured within a process monitor portion of the integrated circuit and the at least one determined analog value is utilized to correct for the process-dependent parameter in an operational portion of the integrated circuit.

- 2. (original) The method according to claim 1, wherein steps (a) and (b) are performed outside of the integrated circuit chip.
- 3. (original) The method according to claim 1, wherein step (b) comprises retrieving the at least one value from a look-up table using the at least one digitized signal.
- 4. (original) The method according to claim 1, wherein step (b) comprises calculating the at least one value from the at least one digitized signal.
- 5. (original) The method according to claim 1, wherein the at least one digitized sense signal represents a gate-to-source threshold voltage of a transistor fabricated on the integrated circuit chip.
- 6. (original) The method according to claim 1, wherein the at least one digitized sense signal represents a transconductance parameter of a transistor fabricated on the integrated circuit chip.

- 7. (original) The method according to claim 1, wherein the at least one digitized sense signal represents a sheet resistance of a resistor fabricated on the integrated circuit chip.
- 8. (original) The method according to claim 1, wherein the at least one digitized sense signal represents a temperature of the integrated circuit chip.
- 9. (original) The method according to claim 1, wherein the at least one digitized sense signal represents a power supply voltage on the integrated circuit chip.
- 10. (original) The method according to claim 1, wherein the at least one digitized sense signal includes a plurality of digitized sense signals that represent a plurality of the following:
- a gate-to-source threshold voltage of a transistor fabricated on the integrated circuit chip;
- a transconductance parameter of a transistor fabricated on the integrated circuit chip;
  - a sheet resistance of a resistor fabricated on the integrated circuit chip;
  - a temperature of the integrated circuit chip; and
  - a power supply voltage on the integrated circuit chip.
- 11. (original) A system for monitoring an integrated circuit chip, comprising:
  means for receiving at least one digitized sense signal from the integrated circuit
  chip, whereby the at least one digitized sense signal represents a corresponding processdependent parameter within the integrated circuit chip; and

means for determining an analog value for the at least one process-dependent circuit parameters from the corresponding at least one digitized signal;

wherein the process-dependent parameter is measured within a process monitor portion of the integrated circuit and the at least one determined analog value is utilized to correct for the process-dependent parameter in an operational portion of the integrated circuit.

- 12. (original) The system according to claim 11, wherein the means for receiving and the means for determining are positioned external of the integrated circuit chip.
- 13. (currently amended) The vaccording system according to claim 11, wherein the means for determining comprises means for retrieving the at least one value from a look-up table using the at least one digitized signal.
- 14. (original) The system according to claim 11, wherein the means for determining comprises means for calculating the at least one value from the at least one digitized signal.
- 15. (original) The system according to claim 11, wherein the at least one digitized sense signal represents a gate-to-source threshold voltage of a transistor fabricated on the integrated circuit chip.
- 16. (original) The system according to claim 11, wherein the at least one digitized sense signal represents a transconductance parameter of a transistor fabricated on the integrated circuit chip.
- 17. (original) The system according to claim 11, wherein the at least one digitized sense signal represents a sheet resistance of a resistor fabricated on the integrated circuit chip.
- 18. (original) The system according to claim 11, wherein the at least one digitized sense signal represents a temperature of the integrated circuit chip.
- 19. (original) The system according to claim 11, wherein the at least one digitized sense signal represents a power supply voltage on the integrated circuit chip.
- 20. (original) The system according to claim 11, wherein the at least one digitized sense signal includes a plurality of digitized sense signals that represent a plurality of the following:

- a gate-to-source threshold voltage of a transistor fabricated on the integrated circuit chip;
- a transconductance parameter of a transistor fabricated on the integrated circuit chip;
  - a sheet resistance of a resistor fabricated on the integrated circuit chip;
  - a temperature of the integrated circuit chip; and
  - a power supply voltage on the integrated circuit chip.